

Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings	Unit
V _{DSS}	100	V
V _{GSS}	±10	V
I _D	±5	A
I _{D(pulse)}	±10 (PW≤1ms)	A
E _{AS*}	60	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink) 35 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{j-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)	Vrms
T _{ch}	150	°C
T _{tsg}	-40 to +150	°C

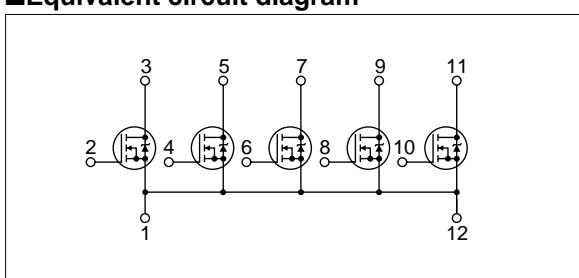
* : V_{DD}=20V, L=10mH, I_D=3A, unclamped, see Fig. E on page 15.

Electrical characteristics

(Ta=25°C)

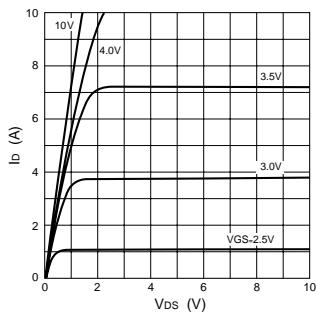
Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	100			V	I _D =250μA, V _{GS} =0V
I _{GSS}			±500	nA	V _{GS} =±10V
I _{DSS}			250	μA	V _{DS} =100V, V _{GS} =0V
V _{TH}	1.0		2.0	V	V _{DS} =10V, I _D =250μA
R _{e(yfs)}	4	6		S	V _{DS} =10V, I _D =5A
R _{Ds(ON)}	0.18	0.19		Ω	V _{GS} =10V, I _D =2.5A
	0.19	0.25		Ω	V _{GS} =4V, I _D =2.5A
C _{iss}	880			pF	V _{DS} =25V, f=1.0MHz,
C _{oss}	240			pF	V _{GS} =0V
t _{on}	90			ns	I _D =5A, V _{DD} =50V, V _{GS} =5V, see Fig. 3 on page 16.
t _{off}	75			ns	
V _{SD}		1.1	1.5	V	I _{SD} =5A, V _{GS} =0V
t _{rr}		500		ns	I _{SD} =±100mA

■ Equivalent circuit diagram

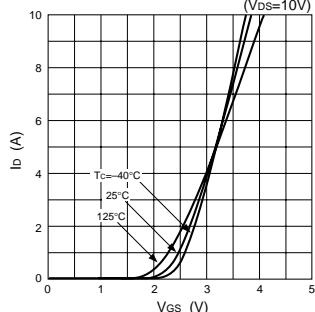


Characteristic curves

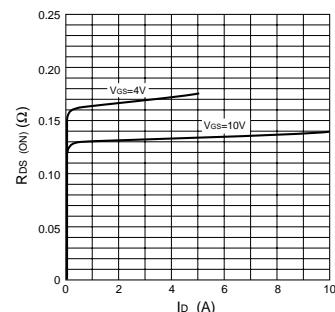
I_D-V_{DS} Characteristics (Typical)



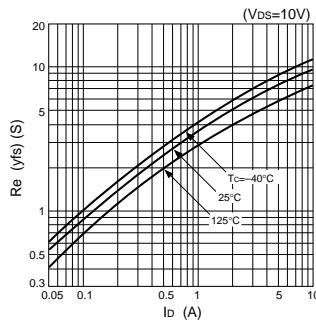
I_D-V_{GS} Characteristics (Typical)



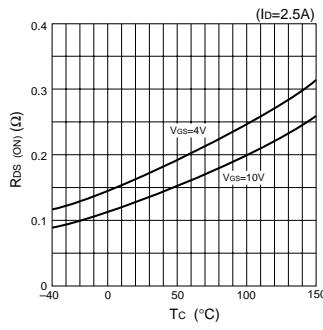
R_{Ds(ON)}-I_D Characteristics (Typical)



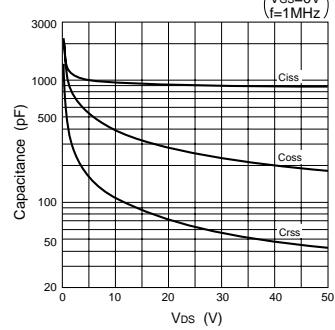
R_{e(yfs)}-I_D Characteristics (Typical)



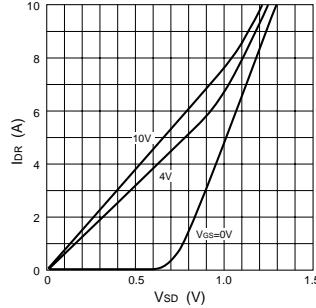
R_{Ds(ON)}-T_c Characteristics (Typical)



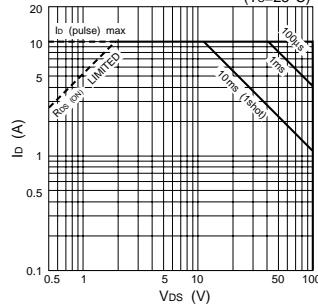
Capacitance-V_{DS} Characteristics (Typical)



I_{DR}-V_{SD} Characteristics (Typical)



Safe Operating Area (SOA)



P_T-T_a Characteristics

